NSN 5961-00-226-8695

Transistor - Page 1 of 2



View Online at https://aerobasegroup.com/nsn/5961-00-226-8695
Inclosure Material:
Metal
Overall Length:
Between 0.195 inches and 0.215 inches
Overall Diameter:
Between 0.440 inches and 0.460 inches
Mounting Facility Quantity:
1
Internal Configuration:
Junction contact
Electrode Internally-electrically Connected To Case:
Collector
Mounting Method:
Threaded stud
Features Provided:
Hermetically sealed case
Thread Size:
0.138 inches
Semiconductor Material:
Silicon
Voltage Rating In Volts Per Characteristic:
80.0 collector to emitter voltage, dc and 10.0 emitter to base voltage, dc
Current Rating Per Characteristic:
500.00 milliamperes source cutoff current
Power Rating Per Characteristic:
40.0 watts small-signal input power, common-collector
Special Features:
Junction pattern arrangement: npn
Test Data Document:
81349-mil-s-19500 specification (includes engineering type bulletins, brochures, etc., that reflect specification type data in specification
format; excludes commercial catalogs, industry directories, and similar trade publications, reflecting general type data on certain
environmental and performance requirements and test conditions that are shown as "typical", "average", "", etc.).
Thread Series Designator:
Unc
Terminal Type And Quantity:
3 uninsulated wire lead
Specification Data:
81349-mil-s-19500/176 government specification
Shelf Life:
N/a
Unit Of Measure:
Demilitarization:

No

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